

0105-100

100 Watts, 28 Volts, Class AB Defcom 100 - 500 MHz

GENERAL DESCRIPTION

The 0105-100 is a double input matched COMMON EMITTER broadband transistor specifically intended for use in the 100-500 MHz frequency band. It may be operated in Class AB or C. Gold metallization and silicon diffused resistors ensure ruggedness and high reliability.

ABSOLUTE MAXIMUM RATINGS

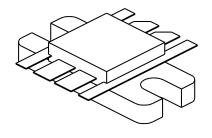
Maximum Power Dissipation @ 25°C 270 Watts

Maximum Voltage and Current

BVces Collector to Emiter Voltage 65 Volts
BVebo Emitter to Base Voltage 4.0 Volts
Ic Collector Current 16 A

Maximum Temperatures

Storage Temperature $-40 \text{ to } +150^{\circ}\text{C}$ Operating Junction Temperature $+200^{\circ}\text{C}$ CASE OUTLINE 55JT, Style 2



ELECTRICAL CHARACTERISTICS @ 25 °C

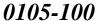
SYMBOL	CHARACTERISTICS	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Pout Pin Pg ηc VSWR	Power Output Power Input Power Gain Efficiency Load Mismatch Tolerance	F = 500 MHz Vcc = 28 Volts	100	18 7.5 50	24 5:1	Watts Watts dB %

BVebo BVces BVceo	Emitter to Base Breakdown Collector to Emitter Breakdown Collector to Emitter Breakdown	Ie = 5 mA Ic = 100 mA Ie = 50 mA	4.0 60 31			Volts Volts Volts
Cob ²	Output Capacitance	Vcb = 28 V, F = 1 MHz	4.0	140		pF
\mathbf{h}_{FE} θ jc	DC - Current Gain Thermal Resistance	Vce = 5 V, Ic = 500 mA	10		0.65	°C/W

Note 2: Both sides together, all other specifications each side tested separately

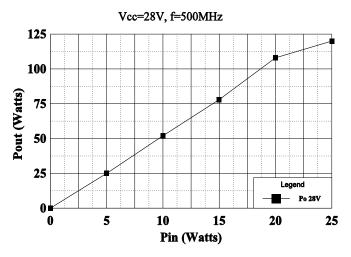
Issue August 1996

GHz TECHNOLOGY INC. RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE. GHZ RECOMMENDS THAT BEFORE THE PRODUCT(S) DESCRIBED HEREIN ARE WRITTEN INTO SPECIFICATIONS, OR USED IN CRITICAL APPLICATIONS, THAT THE PERFORMANCE CHARACTERISTICS BE VERIFIED BY CONTACTING THE FACTORY.

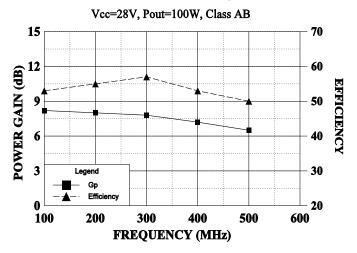




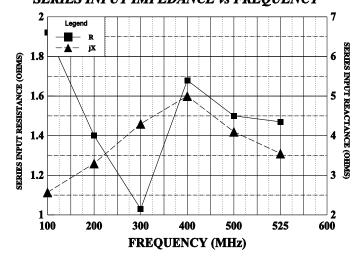
POWER OUTPUT vs POWER INPUT



PERFORMANCE VS FREQUENCY







SERIES LOAD IMPENDANCE vs FREQUENCY

